

Light Emitting Diode(InGaN)

KODENSHI

KLP-342B-X-X

KLP-342B-x-x is a high bright InGaN blue LED, and has the optimized optical characteristics.

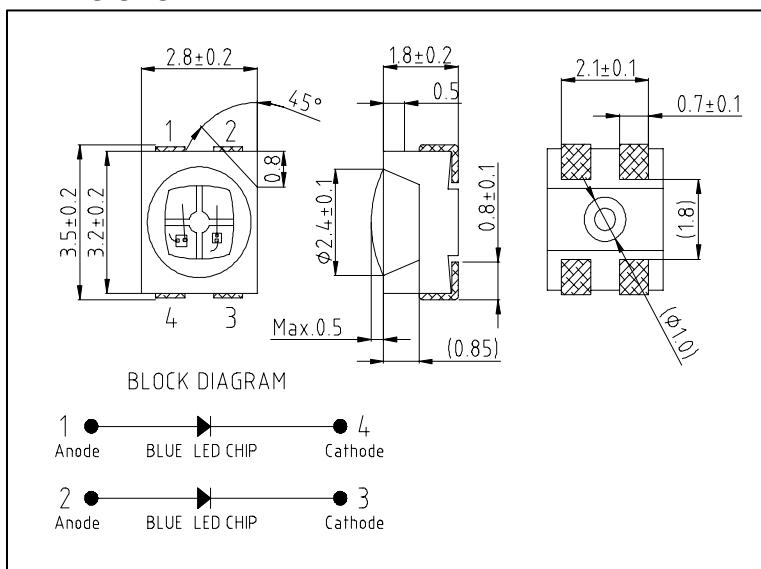
Features

- Transparent epoxy Encapsulent
- High Optical Output

Applications

- Display
- Indicator
- Signage

DIMENSIONS



Maximum Ratings

[Ta=25°C]

Parameter	Symbol	Ratings	Unit
Reverse Voltage (w/o Zener Option)	V _R	5	V
Reverse current (w Zener Option)	I _R	50	mA
Forward current	I _F	30	mA
Pulse forward current ^{*1}	I _{FP}	0.1	A
Power dissipation	P _D	90	mW
Operating temperature	T _{opr.}	-30 ~ +85	°C
Storage temperature	T _{stg.}	-40 ~ +105	°C
Soldering Temperature ^{*2}	T _{sol.}	260	°C

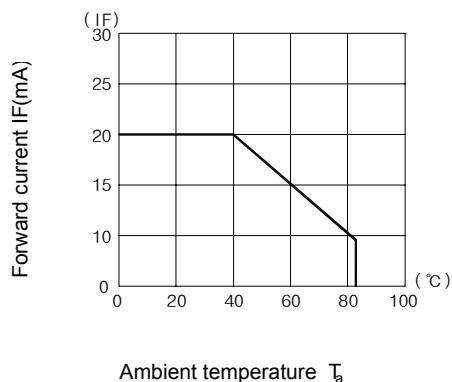
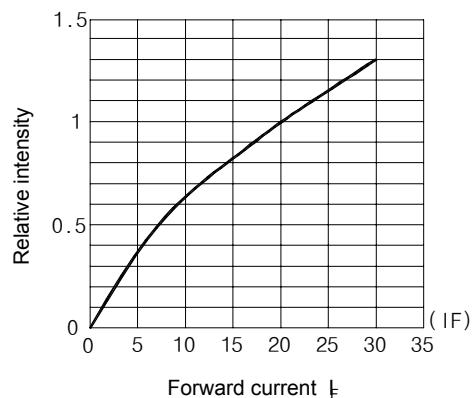
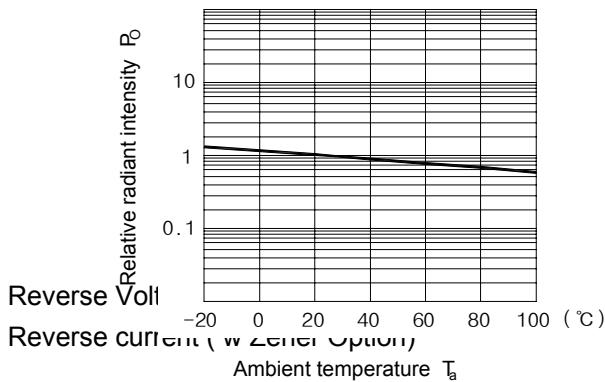
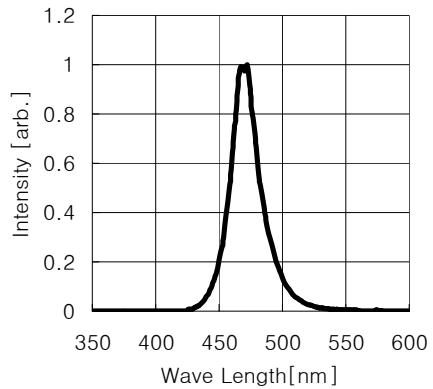
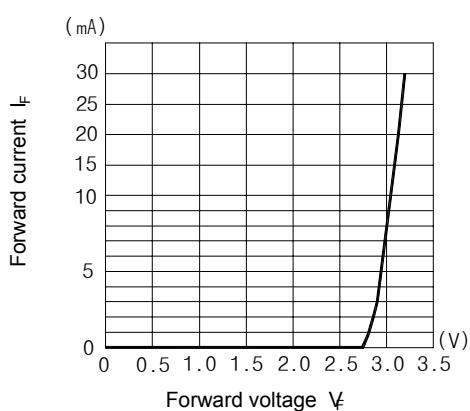
*1. I_{FP} Measured under duty £ 1/10 @ 1KHz

*2. Soldering time £ 5 Sec

Electro-Optical Characteristics

[Ta=25°C]

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward voltage	V _F	I _F = 20 mA	-	3.2	-	V
Optical Output Power	P _O	I _F = 40 mA	9.00	12.00	-	mW
	I _V		350	450	-	mcd
Doninant Wave Length	λ _d	I _F = 20 mA	460	-	470	nm
Spectral half bandwidth	Δλ	I _F = 20 mA	-	25	-	nm
Half angle	Δθ	I _F = 20 mA	-	110	-	deg.

KLP-342B-X-X**Forward current vs.
Ambient temperature****Radiant Intensity vs.
Forward current****Relative radiant intensity vs.
Ambient temperature****Relative intensity vs.
Wavelength****Forward current vs.
Forward voltage****Radiant Pattern
Angle(deg)**